# Reactivity Studies of a Disilene with $\mathrm{N}_{2} \mathrm{O}$ and Elemental Sulfur 

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## (S) Supporting Information


#### Abstract

:  trans- cis- trans- In a previous contribution, we have reported on a convenient and high yield synthesis of the disilene trans-[(TMS) $)_{2} \mathrm{~N}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right)$ -$\left.\mathrm{Si}=\mathrm{Si}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{N}(\mathrm{TMS})_{2}\right]$ (2). Herein, we show the reactions of 2 with $\mathrm{N}_{2} \mathrm{O}$ and $\mathrm{S}_{8}$. The former reaction affords two isomeric (cis- and trans-) dioxadisiletane ring compounds. To the best of our knowledge, this is the first report where both cis- and trans-isomers are isolated from the same disilene precursor and characterized structurally by single-crystal X-ray diffraction (XRD) studies. The reaction of $\mathbf{2}$ with elemental sulfur yields only the trans-isomer. To investigate this dissimilar reaction pattern exhibited by $\mathbf{2}$, computational studies were performed. Density functional theory (DFT) calculations showed that the two dioxadisiletane ring isomers are isoenergetic, with the trans isomer being slightly more stable than the cis counterpart, by $3.3 \mathrm{kcal} / \mathrm{mol}$, while that is not the case with sulfur. All the isolated compounds are characterized by single-crystal XRD studies, multinuclear NMR spectroscopy, and electron ionization-mass spectrometry (EI-MS).


## ■ INTRODUCTION

Since the remarkable isolation of the first stable disilene $\left(\mathrm{Mes}_{2} \mathrm{Si}=\mathrm{SiMes}_{2}, \mathrm{Mes}=2,4,6-\mathrm{Me}_{3} \mathrm{C}_{6} \mathrm{H}_{2}\right)$ by West et al. in 1981, ${ }^{1}$ considerable attention has been paid to developing the chemistry of disilenes. ${ }^{2}$ One of the most commonly used synthetic protocols to access the disilenes is the generation of highly reactive silylenes as intermediates, followed by their dimerization. Therefore, the question arises whether an equilibrium exists between the silylene and the corresponding disilene. This has prompted substantial experimental and theoretical activity, although very few examples are known where an equilibrium is observed between silylene and the corresponding disilene. A first report by Okazaki and co-workers described the thermal dissociation of extremely hindered and kinetically stable disilene $[\mathrm{Tbt}(\mathrm{Mes}) \mathrm{Si}=\mathrm{Si}(\mathrm{Mes}) \mathrm{Tbt}, \mathrm{Tbt}=2,4,6$-tris $\{$ bis (trimethylsilyl)methyl $\}$ phenyl] into very reactive silylene $[\mathrm{Tb}(\mathrm{Mes}) \mathrm{Si}]$ under mild conditions. ${ }^{3}$ Later, the existence of thermal equilibrium between $2,3,4,6,7,8,2^{\prime}, 3^{\prime}, 4^{\prime}, 6^{\prime}, 7^{\prime}, 8^{\prime}$-dodeca-tert-butyl[ $\left.5,5^{\prime}\right]$-bi $\{1$, 5-disilatricyclo[4.2.0.0]-octylidene $\}-2,7,2^{\prime}, 7^{\prime}$-tetraene and the corresponding silylene was proved by trapping experiments and DFT calculations by Tsutsui et al. ${ }^{4 a}$ Kira and co-workers further supported the existence of the equilibrium between disilene and the corresponding silylene by providing strong spectroscopic evidence for the existence of the silylene $\left[\left(\mathrm{R}_{2} \mathrm{~N}\right)_{2} \mathrm{Si}, \mathrm{R}=i \mathrm{Pr}\right]$ in solution which is in equilibrium with the corresponding disilene at low temperature. ${ }^{4 \mathrm{~b}}$ West et al. then reported the existence of dynamic equilibrium between cis-diaminodisilyldisilene and saturated diaminosilylene by ${ }^{29} \mathrm{Si}$ NMR and UV-vis spectroscopy, although diaminosilylene was not the monomer of cis-diaminodisilyldisilene. ${ }^{5}$ Recently, a noteworthy contribution in this field was made by Jutzi et al., describing the unique situation where

## Scheme 1. Preparation of 2


both the silylene $\left[(\mathrm{TMS})_{2} \mathrm{~N}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{Si}\right]$ as well as the corresponding disilene trans- $\left[(\mathrm{TMS})_{2} \mathrm{~N}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{Si}=\mathrm{Si}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right)\right.$ $\mathrm{N}(\mathrm{TMS})_{2}$ ] (2) are stable and isolable under normal conditions, and this transformation can be easily recognized by the phase transfer from solution to solid state. ${ }^{6}$ They explained this unusual behavior on the basis of steric strain in the solid disilene and flexibility in bonding modes ( $\sigma$ or $\pi$ ) of $\mathrm{Cp}^{*}\left(\mathrm{Cp}^{*}=\mathrm{Me}_{5} \mathrm{C}_{5}\right)$ groups. Despite the successful isolation of 2 , chemistry of this unique compound is still in its infancy because of the synthetic constraints associated with the synthesis. ${ }^{6}$ Recently we have successfully resynthesized 2 in $68 \%$ yield in a single step by treatment of $\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{SiHCl}_{2}(\mathbf{1})$ with $\mathrm{KN}(\mathrm{TMS})_{2}$ in a molar ratio of $1: 2$ in toluene (see Scheme 1 ). ${ }^{7}$ The increase in the yield for 2 with the new method allows us to investigate its reactivity.

In the course of our recent studies on the reactions of compounds having low valent silicon atoms with various unsaturated

[^0]
## Scheme 2. Preparation of 3a and 3b


organic compounds, ${ }^{8-10}$ we became interested in investigating the unique reactions of 2 with $\mathrm{N}_{2} \mathrm{O}$ and $\mathrm{S}_{8}$.

## RESULTS AND DISCUSSION

Reaction with Nitrous Oxide. $\mathrm{N}_{2} \mathrm{O}$ is well-known to serve as a mono-oxygen donor. Reaction of $\mathbf{2}$ in toluene with $\mathrm{N}_{2} \mathrm{O}$ at room temperature led to the formation of two dioxadisiletane isomers (cis- and trans-) (see Scheme 2). Analysis of ${ }^{1} \mathrm{H},{ }^{13} \mathrm{C}$, and ${ }^{29} \mathrm{Si}$ NMR ( $\delta 7.32,5.17,3.88,-12.11,-22.31$, and -28.53 $\mathrm{ppm})$ spectral data indicated the presence of two compounds (cis- and trans-isomers) in an approximately 2:3 ratio. The removal of the solvent under vacuum, followed by recrystallization in $n$-pentane, furnished colorless crystals of 3 (a and $\mathbf{b}$ ) suitable for single-crystal X-ray diffraction (XRD) studies. The crystals for the X-ray structural study of the cis and trans isomers were selected by hand from the crystal mixture under microscope. Note that this is the first example where both isomers were formed from the same disilene precursor. West et al. first reported the formation of trans-1,3-di-tert-butyl-1,3-dimesitylcyclodisiloxane from the corresponding trans-disilene and cis-1,3-bis[bis(trimethylsilyl)amino]-1,3-dimesitylcyclodisiloxane from the corresponding cis-disilene. ${ }^{1 \text { aa }}$ The formation of cis-1,3-dioxa-2,4-disiletane ring from corresponding cis-disilene was further documented by Okazaki et al. upon treatment with molecular oxygen. ${ }^{3 c}$ Moreover, we reported the formation of two cyclodisiloxane derivatives from the reactions of $\mathrm{LSiCl}(\mathrm{L}=$ $\mathrm{PhC}(\mathrm{N} t \mathrm{Bu})_{2}$ ) with trimethylamine oxide and tert-butyl isocyanate ${ }^{8 \mathrm{~b}}$ and $\mathrm{L}_{2} \mathrm{Si}_{2}$ with benzophenone. ${ }^{8 \mathrm{c}}$ It is important to mention that, in both cases, we were able to isolate only the trans-isomer.

The presence of two isomers (cis-and trans-) was confirmed by single-crystal XRD studies. Compound 3a crystallizes in the centrosymmetric monoclinic space group $P 2_{1} / n$. ${ }^{12}$ Selected bond lengths and bond angles are given in the legend of Figure 1. The molecular structure of 3a reveals a cis-configured, almostplanar $\mathrm{Si}_{2} \mathrm{O}_{2}$ ring (mean deviation from plane: $0.0214 \AA$ ) with the dihedral angle of $4.1^{\circ}$ between the $\mathrm{O}-\mathrm{Si}-\mathrm{O}$ three-membered planes. The independent endocyclic $\mathrm{Si1}-\mathrm{O} 1-\mathrm{Si} 2, \mathrm{Si1}-\mathrm{O} 2-\mathrm{Si} 2$, $\mathrm{O} 1-\mathrm{Si} 1-\mathrm{O} 2$, and $\mathrm{O} 1-\mathrm{Si} 2-\mathrm{O} 2$ angles are $91.42(4)^{\circ}, 91.29(4)^{\circ}$, $88.34(4)^{\circ}$, and $88.81(4)^{\circ}$, respectively. All four $\mathrm{Si}-\mathrm{O}$ distances fall in the range of $1.6750(8)-1.6840$ (8) $\AA$ and match well with the reported $\mathrm{Si}-\mathrm{O}$ bond lengths for the several dioxadisiletane rings reported in the literature. ${ }^{3 c, 8 b, 8 c, 11}$ The interatomic separation between two silicon atoms ( $\mathrm{Si} \cdots \mathrm{Si}$ ) in the ring is $2.4029(4) \AA$, which is slightly longer than the calculated value for $\mathrm{H}_{4} \mathrm{Si}_{2} \mathrm{O}_{2}$ (calculated $\mathrm{Si}-\mathrm{O}$ and $\mathrm{Si} \cdots$ Si distances range between 1.661 and $1.671 \AA$ and 2.383 and $2.394 \AA$, respectively ${ }^{13 a}$ but significantly shorter than those of the previously reported $\mathrm{L}_{2} \mathrm{Cl}_{2} \mathrm{Si}_{2} \mathrm{O}_{2}{ }^{8 \mathrm{~b}}$ and $\mathrm{L}_{2}\left(\mathrm{CHPh}_{2}\right)_{2} \mathrm{Si}_{2} \mathrm{O}_{2}{ }^{8 \mathrm{c}}\left(\mathrm{L}=\mathrm{PhC}(\mathrm{N} t \mathrm{Bu})_{2}\right)$, where the $\mathrm{Si} \cdot \cdots \mathrm{Si}$ interatomic separations are 2.48 and $2.51 \AA$, respectively. Both of the Si atoms are tetra-coordinated and exhibit distorted tetrahedral geometry. An angle of $79.98^{\circ}$ between the planes of the two


Figure 1. Molecular structure of 3a. Hydrogen atoms are not shown, for the sake of clarity. Anisotropic displacement parameters are depicted at the $50 \%$ probability level. Selected bond distances are given as follows: Sil…Si2, 2.4030(7) Å; Si1-O1, 1.6820(8) Á; Si1-O2, 1.6840(8) $\AA ; \mathrm{Si} 2-\mathrm{O} 1,1.6750(8) \AA ; \mathrm{Si} 2-\mathrm{O} 2,1.6768(8) \AA$; Si1-N1, $1.7182(9) \AA$; Si2-N2, $1.7260(10) \AA$; Si1-C14, $1.8996(11) \AA$; and Si2-C24, 1.9213(11) A. Selected bond angles are given as follows: $\mathrm{O} 1-\mathrm{Si} 1-\mathrm{O} 2,88.34(4)^{\circ}$; $\mathrm{O} 1-\mathrm{Si} 2-\mathrm{O} 2,88.81(4)^{\circ}$; $\mathrm{O} 1-\mathrm{Si} 1-\mathrm{N} 1$, $112.90(4)^{\circ}$; O2-Si1-N1, 114.71(4) ${ }^{\circ}$; N1-Si1-C14, $115.34(4)^{\circ}$; $\mathrm{N} 2-\mathrm{Si} 2-\mathrm{C} 24,111.51(5)^{\circ}$; Si1-O1-Si2, 91.42(4) ${ }^{\circ}$; Si1-O2-Si2, $91.29(4)^{\circ}$; $\mathrm{O} 1-\mathrm{Si} 1-\mathrm{C} 14,112.34(4)^{\circ}$; $\mathrm{O} 2-\mathrm{Sil-C14} ,110.26(4)^{\circ}$; $\mathrm{O} 1-\mathrm{Si} 2-\mathrm{N} 2,113.64(4)^{\circ}$; $\mathrm{O} 2-\mathrm{Si} 2-\mathrm{N} 2,112.11(4)^{\circ} ; \mathrm{O} 1-\mathrm{Si} 2-\mathrm{C} 24$, $113.42(4)^{\circ}$; O2-Si2-C24, 115.65(4) ${ }^{\circ}$; C26-C24-Si2, 114.26(7) ${ }^{\circ}$; and C16-C14-Sil, 106.91(7) ${ }^{\circ}$.

Cp * rings (attached to two different Si atoms) discloses that these two $\mathrm{Cp}^{*}$ are almost perpendicular to each other.

Compound $\mathbf{3 b}$ crystallizes in the centrosymmetric monoclinic space group $P 2_{1} / n$ and selected bond lengths and bond angles are given in the legend of Figure $2 .{ }^{12}$ The molecular structure of $\mathbf{3 b}$ displays the trans-configuration of $\mathrm{Cp}^{*}$ and $\mathrm{N}(\mathrm{TMS})_{2}$ groups attached to the four-membered $\mathrm{Si}_{2} \mathrm{O}_{2}$ ring. The $\mathrm{Si}_{2} \mathrm{O}_{2}$ ring is planar (mean deviation from plane is $0^{\circ}$ due to a center of symmetry between Sil and SilA). The independent endocyclic $\mathrm{Si}-\mathrm{O}-\mathrm{Si}$ and $\mathrm{O}-\mathrm{Si}-\mathrm{O}$ bond angles are $90.55(8)^{\circ}$ and $89.45(8)^{\circ}$, respectively. Another important feature is the bond distance between two Si atoms ( 2.3859 (11) $\AA$ ), which matches well with the calculated value $(2.383-2.394 \AA)^{13 \mathrm{a}}$ and also with the cis-counterpart. The $\mathrm{Si}-\mathrm{O}$ bond lengths fall between $1.6762(16) \AA$ and $1.6819(15) \AA$, and are consistent with those found for 3 a and other $\mathrm{Si}_{2} \mathrm{O}_{2}$ rings. ${ }^{3 c, 8 b, 8 c, 11}$ Both Si atoms are tetra-coordinated with distorted tetrahedral geometry and complete their coordination sphere with two O atoms of the fourmembered $\mathrm{Si}_{2} \mathrm{O}_{2}$ ring, one $\mathrm{Cp}^{*}$ ring and one nitrogen atom of the $\mathrm{N}(\mathrm{TMS})_{2}$ group.

In order to understand the formation of two isomeric compounds in the same reaction, DFT calculations were performed. Reaction of 2c (DFT optimized structure of 2) with $\mathrm{N}_{2} \mathrm{O}$ yielded for the first time the cis-(3ac) and trans-(3bc) isomers of $\mathrm{Si}_{2} \mathrm{O}_{2}$ rings (vide supra, Figure 3). The isomers are iso-energetic with the trans-isomer 3bc slightly more stable than the cis-counterpart 3 ac , by $3.3 \mathrm{kcal} / \mathrm{mol}$. There are mainly three mechanisms possible to explain the formation of the products.

According to the first mechanism, 2 c will react with one molecule of $\mathrm{N}_{2} \mathrm{O}$ to yield the $\mathrm{Si}_{2} \mathrm{O}$ ring product $3-1 \mathbf{c}$ (Figure 3). The reaction


Figure 2. Molecular structure of $\mathbf{3 b}$. Hydrogen atoms and disordered moieties are not shown for clarity. Atoms labeled with an "A" are symmetry-generated by inversion between related atoms. Anisotropic displacement parameters are depicted at the $50 \%$ probability level. Selected bond distances are given as follows: Sil $\cdots$. SilA, $2.3859(11) ~ \AA ̊ ; ~ S i 1-O 1$, 1.6819 (15) $\AA$; Sil-O1A, $1.6762(16) ~ \AA ̊ ; ~ S i 1-N 1,1.7205(18) ~ \AA ̊ ;$ and Sil-C1, $1.910(3) \AA$. Selected bond angles are given as follows: O1-Sil-O1A, $89.45(8)^{\circ}$; N1-Sil-O1A, $114.59(8)^{\circ}$; N1-Si1-O1, $114.62(8)^{\circ}$; $\mathrm{C} 1-\mathrm{Sil}-\mathrm{O} 1 \mathrm{~A}, 110.94(10)^{\circ}$; $\mathrm{C} 1-\mathrm{Si1}-\mathrm{O} 1,108.67(10)^{\circ}$; N1-Sil-C1, 115.63(10) ; and Si1-O1-SilA, $90.55(8)^{\circ}$.


Figure 3. BP86/SVP optimized structures of the intermediates obtained during $\mathrm{N}_{2} \mathrm{O}$ reaction. The values in parentheses are the electronic energy relative to the starting species 2c calculated at BP86/TZVP// BP86/SVP level of theory. Color code: C gray, O red, N blue and Si pink. Hydrogens are removed for the sake of clarity.
energy $\left(\Delta E_{\mathrm{e}}=\left\{\Sigma E_{\text {products }}-\sum E_{\text {reactants }}\right\}\right)$ for the transformation $(2 c \rightarrow 3-1 c)$ is $-107.5 \mathrm{kcal} \mathrm{mol}^{-1}$. This reaction is facilitated with the easy removal of $\mathrm{N}_{2}$ when $\mathrm{N}_{2} \mathrm{O}$ approaches disilene moiety 2 c . Further elongation of the $\mathrm{Si}-\mathrm{Si}$ bond in $3-1 \mathrm{c}$ yielded $3-2 \mathrm{c}$, which possesses a quasi-linear $\mathrm{Si}-\mathrm{O}-\mathrm{Si}$ unit ( $\mathrm{Si}-\mathrm{O}-$ $\mathrm{Si}=144.8^{\circ}$ ). The energy barrier for this transformation (see Computational Details in the Supporting Information) is roughly $30.6 \mathrm{kcal} / \mathrm{mol}$, and $3-2 \mathrm{c}$ is energetically $27.5 \mathrm{kcal} / \mathrm{mol}$ less stable than $3-1 \mathrm{c}$. Rotation about the $\mathrm{Si}-\mathrm{O}$ bond furnished the isoenergetic cis-isomer 3-3c (Figure 3). This isomer undergoes rapid transformation to form $3-4 \mathrm{c}$, which is the cis-variant of the isomer 3-1c. Intermediate 3-4c can then further react with another $\mathrm{N}_{2} \mathrm{O}$ molecule to form 3ac. The energetics and the respective stabilities of all the important intermediates are depicted in Figure 3. The more stable trans-product 3bc is obtained when 3-1c species directly undergoes a second



Figure 4. BP86/SVP optimized structures of the disilene 2 and in-situgenerated silylene $\left(\mathbf{2} \mathbf{c}_{\mathrm{m}}\right)$. The values in parentheses are the electronic energy relative to the starting species 2c calculated at BP86/TZVP// BP86/SVP level of theory. Color code: C, gray, P, green, N , blue and Si , pink. Hydrogens are removed for the sake of clarity.
addition of oxygen atom from the $\mathrm{N}_{2} \mathrm{O}$ moiety. However, this transformation entails an activation barrier of roughly $32 \mathrm{kcal} /$ mol and, hence, will be energetically competitive with the $3-1 \mathrm{c} \rightarrow$ $3-2 \mathrm{c}$ reaction step.

In the second mechanism, the disilene 2 c might undergo dissociation to form the respective silylenes (Figure 4) ( $2 c_{m}$ ) that can further recombine to form the cis-variant of 2 c . The calculated disilene-silylene barrier $\left(2 \mathrm{c} \rightarrow 2 \times 2 \mathrm{c}_{\mathrm{m}}\right)$ is $22 \mathrm{kcal} /$ mol at the BP86/TZVP//BP86/SVP level of theory. It might be a viable pathway, since such types of dissociation-recombination steps are known for tetraaryldisilene. ${ }^{3 a}$ Subsequent addition of the two $\mathrm{N}_{2} \mathrm{O}$ units can occur to both the cis- and trans-disilene isomers to yield the respective products $3 \mathbf{b c}$ and $3 \mathbf{a c}$.

Finally, we have considered the cis-trans isomerization of disilenes via the rotation around the $\mathrm{Si}=\mathrm{Si}$ bond. The calculated rotational barrier for such isomerization is roughly $18 \mathrm{kcal} / \mathrm{mol}$. Indeed, this mechanistic route is feasible and the barrier calculated shows similar value ( $\sim 15 \mathrm{kcal} / \mathrm{mol}$ ) observed by Kira et al. while performing dynamic NMR studies with tetrakis(trialkylsilyl)disilene species. ${ }^{14}$

Reaction with Elemental Sulfur. Insertion of sulfur into the $\mathrm{Si}=\mathrm{Si}$ double bond is not so common in the literature for atoms such as oxygen, but there are some examples where disilene was reacted with sulfur to afford dithiadisiletane derivatives. ${ }^{15}$ In a recent article, Tokitoh et al. reported the formation of dithiasilarane and 1,3-dithia-2,4-disiletane derivatives by treatment of sulfur with 1,2-bis(ferrocenyl)disilene $[\operatorname{Tip}(\mathrm{Fc}) \mathrm{Si}=\mathrm{Si}(\mathrm{Fc}) \mathrm{Tip}$, Tip $\left.=2,4,6-i \mathrm{Pr}_{3} \mathrm{C}_{6} \mathrm{H}_{2}\right] .{ }^{16}$ Theoretical calculation on the relative reaction heat of sulfurization of the previously mentioned disilene predicted 1,3-dithia-2,4-disiletane derivative as the thermodynamic product, but experimentally that derivative remained elusive. ${ }^{16}$ Reaction of disilene 2 with elemental sulfur in THF produced 1,3-dithia-2,4-disilacyclobutane (4) in $60 \%$ yield (see Scheme 3). Recrystallization in n-pentane afforded colorless crystals of 4 suitable for single-crystal XRD studies. Compound 4 is sparingly soluble in common organic solvents and stable under a dinitrogen atmosphere at room temperature. In the ${ }^{29} \mathrm{Si}$ NMR spectrum, a characteristic resonance was observed at $\delta=$ 6.15 ppm . The upfield shift in the ${ }^{29} \mathrm{Si}$ NMR spectrum compared to $\mathbf{3 a}$ and $\mathbf{3 b}$ is presumably due to the replacement of oxygen by sulfur. Moreover, it also indicates the presence of only one product in the reaction mixture. The molecular ion was observed in the EI-MS spectrum at $m / z 710$ with low intensity.

Compound 4 crystallizes in the triclinic space group $P \overline{1} .{ }^{12}$ The molecular structure of 4 reveals the trans-configured planar $\mathrm{Si}_{2} \mathrm{~S}_{2}$

## Scheme 3. Preparation of 4



Figure 5. Crystal structure of 4. Hydrogen atoms are not shown for the sake of clarity. Anisotropic displacement parameters are depicted at the $50 \%$ probability level. Selected bond distances are given as follows:
 S2-Si2, 2.1460(18) Å; S2-Si1, 2.1448(18) Å; Si1-N1, 1.720(4) $\AA$; $\mathrm{Si} 2-\mathrm{N} 2,1.721(4) \AA$; Sil-C12, 1.940(4) $\AA$; and Si2-C2, 1.932(4). Selected bond angles are given as follows: Si1-S1-Si2, 84.85(7) ${ }^{\circ}$; Sil-S2-Si2, 84.73(7) ${ }^{\circ}$; S1-Sil-S2, 95.20(7) ${ }^{\circ}$; S1-Si2-S2, 95.21 (7) ${ }^{\circ}$; N1-Si1-S2, 110.57(13) ${ }^{\circ}$; N1-Si1-S1, 114.80(12) ${ }^{\circ}$; C12-Si1-S1, $106.72(14)^{\circ}$; $\mathrm{C} 12-\mathrm{Si1}-\mathrm{S} 2,111.25(14)^{\circ}$; $\mathrm{N} 2-\mathrm{Si2}-\mathrm{S} 1,115.36(13)^{\circ}$; N2-Si2-S2, 110.52(12) ${ }^{\circ}$; and N2-Si2-C2, 115.41(18) ${ }^{\circ}$.
ring (see Figure 5). The $\mathrm{Si}-\mathrm{S}-\mathrm{Si}$ bond angles are $84.73(7)^{\circ}$ and $84.85(7)^{\circ}$, respectively, which are even more acute than the corresponding angle in $\mathbf{3 b}\left(90.55^{\circ}\right)$. The $\mathrm{Si}_{2} \mathrm{~S}_{2}$ unit in $\mathbf{4}$ is planar, with a mean deviation of $0.0012 \AA$ from the plane, which is different from the previously reported $\mathrm{Si}-\mathrm{S}-\mathrm{Si}-\mathrm{S}$ rhombus of $1,3,2,4$-dithiadisiletane derivative. ${ }^{15 \mathrm{~d}}$ Both Si atoms of 4 display distorted tetrahedral geometry and are attached to two $S$ atoms, one N atom of the $\mathrm{N}(\mathrm{TMS})_{2}$ group, and one $\mathrm{Cp}{ }^{*}$ group to complete the tetra-coordinated mode. All $\mathrm{Si}-\mathrm{S}$ bonds are of equal lengths (mean $=2.14 \AA$ ) and comparable with the typical $\mathrm{Si}-\mathrm{S}$ single bonds reported in the literature ${ }^{17}$ and longer than that of the first reported silanethione, $\mathrm{Tbt}(\mathrm{Tip}) \mathrm{Si}=\mathrm{S}(\mathrm{Tbt}=$ $\left.\left.2,4,6-\left[(\mathrm{TMS})_{2} \mathrm{CH}\right]_{2} \mathrm{C}_{6} \mathrm{H}_{2}\right), \mathrm{Tip}=2,4,6-i \mathrm{Pr}_{3} \mathrm{C}_{6} \mathrm{H}_{2}\right](1.948(4) \AA) .{ }^{15 c}$

Reaction of $\mathrm{S}_{8}$ with 2 follows a similar mechanistic route as that discussed previously with $\mathrm{N}_{2} \mathrm{O} .2$ reacts with $\mathrm{S}_{8}$ to yield the three-membered complex $4-1 \mathrm{c}$, which is the sulfur analogue of $3-1 \mathbf{c}$. The reaction energy ( $\Delta E_{\mathrm{e}}$ ) for this transformation ( $2 \mathrm{c} \rightarrow$ $4-1 \mathrm{c}$ ) is $-53.5 \mathrm{kcal} / \mathrm{mol}$ (see Figure 6). Similar $\mathrm{Si}-\mathrm{Si}$ bond elongation produced $\mathbf{4 - 2 c}$, which is $30.3 \mathrm{kcal} / \mathrm{mol}$ less stable than $4-1 \mathrm{c}$ and requires an activation barrier of $\sim 35 \mathrm{kcal} / \mathrm{mol}$. This particular reaction is comparatively more energy-demanding and witnesses a higher activation barrier than its oxygen variant (3-1c $\rightarrow \mathbf{3 - 2 c}$ ). Further rotation about the $\mathrm{Si}-\mathrm{S}$ bond furnished the cis-isomer, $4-3 \mathrm{c}$. The cis-isomer is unstable, compared to $4-2 \mathrm{c}$, by a value of $6.3 \mathrm{kcal} / \mathrm{mol}$, making this rearrangement less facile than its oxygen analogue (vide supra). Further contraction of the $\mathrm{Si}-\mathrm{Si}$ bond allows the formation of


4e (-105.2)


4d (-68.1)

4-1c (-53.5)


Figure 6. BP86/SVP-optimized structures of the intermediates obtained during $\mathrm{S}_{8}$ reaction. The values in parentheses are the electronic energy relative to the starting species 2 calculated at BP86/TZVP// BP86/SVP level of theory. Color code: C, gray; S, yellow; N, blue; and Si, pink. Hydrogens are removed for the sake of clarity.


Figure 7. KS-HOMO of $\mathbf{3 - 4 c}$ and $\mathbf{4 - 4 c}$ (isodensity $=0.03$ electron/ bohr ${ }^{3}$ ).
$4-4 \mathrm{c}$, which is $-44.4 \mathrm{kcal} / \mathrm{mol}$ more stable than the starting material. However, the addition of a second $S$ atom to $4-4 \mathrm{c}$ to yield the cis-isomer of $\mathbf{4 c}$ is not facilitated, because the highest occupied molecular orbital (HOMO) of 4-4c does not possess the $\pi$ molecular orbital (MO) over the $\mathrm{Si}-\mathrm{Si}$ bond. To explain the unique bonding feature in disilaoxirane, the Dewar-ChattDuncanson (DCD) model is invoked. ${ }^{18}$ In contrast, the HOMO of $3-4 \mathrm{c}$ contains the bonding $\pi$-orbital over the Si atoms (see Figure 7), which allows electron donation ( $\sigma$-bonding) to the electronegative O atom. ${ }^{13 \mathrm{~b}}$ This remains one of the important factors why the cis-isomer of 4 c (Figure 6) is not observed when 2 reacts with $\mathrm{S}_{8}$, apart from the fact that the energetics for the $\mathrm{S}_{8}$ activation process are comparatively high.

Moreover, the reaction of 2 with $S_{8}$ could yield $\mathbf{4 d}$, with a reaction energy of $-68.1 \mathrm{kcal} / \mathrm{mol}$; however, it has been previously reported by Suzuki et al. ${ }^{15 b}$ that species of the type 4 d are prone to dimerization.

## - CONCLUSION

We have successfully demonstrated the reaction of trans$\left[(\mathrm{TMS})_{2} \mathrm{~N}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{Si}=\mathrm{Si}\left(\eta^{1}-\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{N}(\mathrm{TMS})_{2}\right.$ ] with $\mathrm{N}_{2} \mathrm{O}$ and $\mathrm{S}_{8}$ to give cis- and trans-disilaoxetane rings and the transdithiasiletane ring, respectively. To the best of our knowledge, this is the first example where two isomeric (cis-and trans-) $\mathrm{Si}_{2} \mathrm{O}_{2}$ ring compounds were isolated from the same disilene starting material. It is noteworthy to mention that the oxidative addition of 2 with $\mathrm{S}_{8}$ afforded only the trans-dithiadisiletane ring. The formation of the above-mentioned different products was further explained by computational studies. All the compounds were
well-characterized by multinuclear NMR spectroscopy, EI-MS spectrometry, elemental analysis, and single-crystal X-ray diffraction (XRD) studies.

## ■ EXPERIMENTAL SECTION

All manipulations were carried out in an inert atmosphere of dinitrogen $\left(\mathrm{N}_{2}\right)$, using standard Schlenk techniques and in a $\mathrm{N}_{2}$-filled glovebox. Solvents were purified using a MBRAUN Model MB SPS-800 solvent purification system. All chemicals purchased from Aldrich were used without further purification. ${ }^{1} \mathrm{H},{ }^{13} \mathrm{C}$, and ${ }^{29} \mathrm{Si} \mathrm{NMR}$ spectra were recorded in $\mathrm{C}_{6} \mathrm{D}_{6}$ with a Bruker Model Avance DPX 200 spectrometer or a Bruker Model Avance DRX 500 spectrometer. The chemical shifts $\delta$ are given relative to $\mathrm{SiMe}_{4}$. EI-MS spectra were obtained using a Finnigan MAT 8230 instrument. Elemental analyses were performed by the Institut für Anorganische Chemie, Universität Göttingen. Melting points were measured in a sealed glass tube on a Büchi Model B-540 melting point apparatus.

Preparation of Compounds 3a and 3b. Dry $\mathrm{N}_{2} \mathrm{O}$ was bubbled into a solution of $2(0.646 \mathrm{~g}, 1 \mathrm{mmol})$ in toluene $(40 \mathrm{~mL})$ at room temperature. After 5 min the gas flow of $\mathrm{N}_{2} \mathrm{O}$ was disconnected, and the solution was stirred for further 6 h . All the volatiles were removed in vacuo and $n$-pentane ( 40 mL ) was added to the residue. The solution was concentrated to ca. 3 mL and stored at $-30^{\circ} \mathrm{C}$ in a freezer for few days to yield colorless crystals of $\mathbf{3 a}$ and $\mathbf{3 b}(0.30 \mathrm{~g}, 44 \%) . \mathrm{Mp} 135^{\circ} \mathrm{C}$ (decomp). ${ }^{1} \mathrm{H} \operatorname{NMR}\left(500 \mathrm{MHz}, \mathrm{C}_{6} \mathrm{D}_{6}, 25^{\circ} \mathrm{C}\right): \delta 0.24-0.38(\mathrm{~m}, 36 \mathrm{H}$, $\left.\mathrm{Si} M e_{3}\right), 1.60-1.81\left(\mathrm{br}, 30 \mathrm{H}, M e_{5} \mathrm{C}_{5}\right) \mathrm{ppm} ;{ }^{13} \mathrm{C}\left\{{ }^{1} \mathrm{H}\right\} \mathrm{NMR}(125.75 \mathrm{MHz}$, $\left.\mathrm{C}_{6} \mathrm{D}_{6}, 25{ }^{\circ} \mathrm{C}\right): \delta 1.36\left(\mathrm{Me}_{3} \mathrm{Si}\right), 3.82\left(\mathrm{Me}_{3} \mathrm{Si}\right), 5.82\left(\mathrm{Me}_{3} \mathrm{Si}\right), 11.37$ $\left(M e_{5} \mathrm{C}_{5}\right), 14.25\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right), 22.69\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right), 129.27\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right), 131.91$ $\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right), 136.84\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{ppm} ;{ }^{29} \mathrm{Si}\left\{{ }^{1} \mathrm{H}\right\}$ NMR $\left(99.36 \mathrm{MHz}, \mathrm{C}_{6} \mathrm{D}_{6}\right.$, $\left.25^{\circ} \mathrm{C}\right): \delta 7.32\left(\mathrm{SiMe}_{3}\right), 5.17\left(\mathrm{SiMe}_{3}\right), 3.88\left(\mathrm{SiMe}_{3}\right),-12.11,-22.31$, $-28.53\left(\mathrm{Si}_{2} \mathrm{O}_{2}\right)$ ppm. EI-MS: $m / z: 678\left[\mathrm{M}^{+}\right](100 \%)$. Anal. Calcd for $\mathrm{C}_{32} \mathrm{H}_{66} \mathrm{~N}_{2} \mathrm{O}_{2} \mathrm{Si}_{6}$ (678.37): C, 56.57; H, 9.79; N, 4.12; Found: C, 56.11; H, 9.52; N, 4.18 .

Note: Despite of repeated attempts, we could not separate these two isomers to record the pure spectra separately for each isomer.

Preparation of Compound 4. A solution of $2(0.646 \mathrm{~g}, 1.0 \mathrm{mmol})$ in THF $(20 \mathrm{~mL})$ was added to a stirred suspension of elemental sulfur ( $0.064 \mathrm{~g}, 0.25 \mathrm{mmol})$ in THF $(10 \mathrm{~mL})$. The reaction mixture was stirred at room temperature for 14 h until the solution became colorless. Removal of the solvent, followed by extraction with $n$-pentane ( 25 mL ), gave a colorless solution. The solution was concentrated to ca. 2 mL and stored at $-32{ }^{\circ} \mathrm{C}$ in a freezer for $2-3$ days to afford colorless crystals of 4 ( $0.43 \mathrm{~g}, 60 \%$ ). Mp $140{ }^{\circ} \mathrm{C}$ (decomp). ${ }^{1} \mathrm{H} \operatorname{NMR}\left(500 \mathrm{MHz}, \mathrm{C}_{6} \mathrm{D}_{6}\right.$, $\left.25{ }^{\circ} \mathrm{C}\right): \delta 0.17\left(\mathrm{~s}, 36 \mathrm{H}, \mathrm{Si} M e_{3}\right), 1.65\left(\mathrm{~s}, 30 \mathrm{H}, M e_{5} \mathrm{C}_{5}\right) \mathrm{ppm} ;{ }^{13} \mathrm{C}\left\{{ }^{1} \mathrm{H}\right\}$ NMR ( $\left.125.75 \mathrm{MHz}, \mathrm{C}_{6} \mathrm{D}_{6}, 25^{\circ} \mathrm{C}\right): \delta 1.38\left(\mathrm{Me} \mathrm{Si}^{2}\right), 11.57\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right)$, $129.27\left(\mathrm{Me}_{5} \mathrm{C}_{5}\right) \mathrm{ppm} ;{ }^{29} \mathrm{Si}\left\{{ }^{1} \mathrm{H}\right\}$ NMR ( $\left.99.36 \mathrm{MHz}, \mathrm{C}_{6} \mathrm{D}_{6}, 25^{\circ} \mathrm{C}\right): \delta$ $3.88\left(\mathrm{SiMe}_{3}\right),-6.11\left(\mathrm{Si}_{2} \mathrm{~S}_{2}\right) \mathrm{ppm}$. EI-MS: m/z: $710\left[\mathrm{M}^{+}\right]$(33\%), 575 $\left[\mathrm{M}^{+}-\mathrm{Cp}^{*}\right]$ (100\%). Anal. Calcd for $\mathrm{C}_{32} \mathrm{H}_{66} \mathrm{~N}_{2} \mathrm{~S}_{2} \mathrm{Si}_{6}$ (711.53): C, 54.02; H, 9.35; N, 3.94; Found: C, 53.94; H, 9.30; N, 3.91.

Crystal Structure Determination. Crystals of 3a and $\mathbf{3 b}$ were selected from the recrystallized crude product under microscopic examination, on the basis of their different shape (rhombohedral and needle-shaped crystals were present in the crude mixture). Shock cooled crystals were mounted under nitrogen atmosphere using the X-TEMP2 system. ${ }^{12}$ The data for $3 \mathbf{a}, \mathbf{3 b}$, and 4 were collected at $100(2) \mathrm{K}$ on a INCOATEC Mo Microsource ${ }^{19}$ with Quazar mirror optics and APEX II detector on a D8 goniometer. The diffractometer was equipped with a low-temperature device and used Mo K $\alpha$ radiation $(\lambda=0.71073 \AA)$. The data of $3 \mathbf{a}, 3 \mathrm{~b}$, and 4 were integrated with $\operatorname{SAINT}^{20 a}$ and an empirical absorption with $\operatorname{SADABS}{ }^{20 \mathrm{~b}}$ was applied. The structures were solved by direct methods (SHELXS-97) and refined by full-matrix least-squares methods against $F^{2}$ (SHELXL-97). ${ }^{21}$ Crystal data of 3a: $\mathrm{C}_{32} \mathrm{H}_{66} \mathrm{~N}_{2} \mathrm{O}_{2}$ $\mathrm{Si}_{6}, M=679.41 \mathrm{~g} / \mathrm{mol}$, monoclinic, space group $P 2_{1} / n, a=11.535(2) \AA$,
$b=15.483(2) \AA, c=22.378(2) \AA, \alpha=90^{\circ}, \beta=97.54(2), \gamma=90^{\circ}$, $V=3962.1(9) \AA^{3}, Z=4, \rho_{\text {calc. }}=1.139 \mathrm{Mg} / \mathrm{m}^{3}, \mu=0.240 \mathrm{~mm}^{-1}, F(000)$ : 1488, $\theta$-range: $1.60^{\circ}-31.06^{\circ}$, refl. coll.: 84348 , indep. refl.: 12685 , data/restraints/parameters: $12685 / 0 / 401$, goodness-of-fit (GOOF) on $F^{2}: 1.058, R$-indices $[I>2 \sigma(I)]: R_{1}=0.0346 / w R_{2}=0.0907, R$-indices (all data): $R_{1}=0.0427 / w R_{2}=0.0952$, largest peak/deepest hole: $0.578 /-0.283$ e $\AA^{-3} .3 \mathrm{~b}: \mathrm{C}_{32} \mathrm{H}_{66} \mathrm{~N}_{2} \mathrm{O}_{2} \mathrm{Si}_{6}, M=679.41 \mathrm{~g} / \mathrm{mol}$, monoclinic, space group $P 2_{1} / n, a=9.169(2) \AA, b=13.640(2) \AA, c=15.669(2) \AA$, $\alpha=90^{\circ}, \beta=90.73(2), \gamma=90^{\circ}, V=1959.5(6) \AA^{3}, Z=2, \rho_{\text {calc. }}=1.152$ $\mathrm{Mg} / \mathrm{m}^{3}, \mu=0.242 \mathrm{~mm}^{-1}, F(000): 744, \theta$-range: $1.98^{\circ}-26.36^{\circ}$, refl. coll.: 18 406, indep. refl.: 4007, data/restraints/parameters: 4007/753/ 353, GOOF on $F^{2}: 1.030, R$-indices $[I>2 \sigma(I)]: R_{1}=0.0422 / w R_{2}=$ 0.1035, $R$-indices (all data): $R_{1}=0.0572 / w R_{2}=0.1121$, largest peak/ deepest hole: $0.361 /-0.278 \mathrm{e}^{-3} .4: \mathrm{C}_{32} \mathrm{H}_{66} \mathrm{~N}_{2} \mathrm{~S}_{2} \mathrm{Si}_{6}, M=711.53 \mathrm{~g} /$ mol, triclinic, space group $P \overline{1}, a=10.384(6) \AA, b=12.874(7) \AA$, $c=16.360(9) \AA, \alpha=72.12(2)^{\circ}, \beta=78.51(2)^{\circ}, \gamma=75.56(2)^{\circ}$, $V=1997.8(19) \AA^{3}, Z=2, \rho_{\text {calc. }}=1.183 \mathrm{Mg} \mathrm{m}^{-3}, \mu=0.338 \mathrm{~mm}^{-1}$, $F(000): 776, \theta$-range: $1.32^{\circ}-20.87^{\circ}$, refl. coll.: 21707 , indep. refl.: 4202, data/restraints/parameters: 4202/0/401, GOOF on $F^{2}: 1.045, R$-indices $[I>2 \sigma(I)]: R_{1}=0.0430 / w R_{2}=0.1016, R$-indices (all data): $R_{1}=$ $0.0636 / w R_{2}=0.1116$, largest peak/deepest hole: 0.347/-0.365 e $\AA^{-3}$. Crystallographic data (excluding structure factors) for the structures reported in this paper have been deposited with the Cambridge Crystallographic Data Centre (CCDC) as supplementary publications (Nos. 832194 (3a), 832195 (3b), and 832193 (4). Copies of the data can be obtained free of charge upon application to the CCDC, 12 Union Road, Cambridge CB2 1EZ, U.K. (fax, (internat.) +44(1223)336-033; E-mail, deposit@ccdc.cam.ac.uk).

## ■ ASSOCIATED CONTENT

(s) Supporting Information. Computational details and CIF files for 3a, 3b, and 4. This material is available free of charge via the Internet at http://pubs.acs.org.

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